## TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

# 2 S C 2 9 8 3

#### POWER AMPLIFIER APPLICATIONS

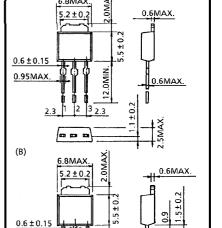
### DRIVER STAGE AMPLIFIER APPLICATIONS

• High Transition Frequency : f<sub>T</sub> = 100 MHz (Typ.)

• Complementary to 2SA1225

### MAXIMUM RATINGS (Tc = 25°C)

CHARACT	SYMBOL	RATING	UNIT		
Collector-Base Voltage		$v_{\mathrm{CBO}}$	160	V	
Collector-Emitter Voltage		$v_{CEO}$	160	V	
Emitter-Base Voltage		$v_{ m EBO}$	5	V	
Collector Current		$I_{\mathbf{C}}$	1.5	A	
Base Current		$I_{\mathbf{B}}$	0.3	A	
Collector Power	$Ta = 25^{\circ}C$	Da	1.0	w	
Dissipation	$Tc = 25^{\circ}C$	PC	15	] **	
Junction Temperature		$T_{j}$	150	°C	
Storage Temperature Range		$T_{ m stg}$	-55~150	°C	



Unit in mm

0.6±0.15

2.3

2.3

2.3

3.4

4.7

5.7

1. BASE

2. COLLECTOR

(HEAT SINK)

3. EMITTER

JEDEC

JEDEC

0.95MAX

**JEITA** 

TOSHIBA (A) 2-7B1A (B) 2-7B2A

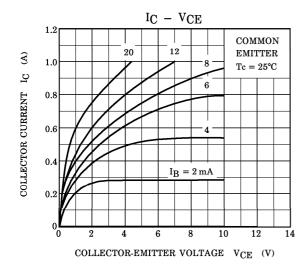
Weight: 0.36 g (Typ.)

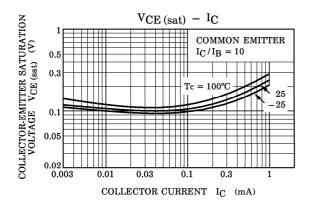
# ELECTRICAL CHARACTERISTICS (Tc = 25°C)

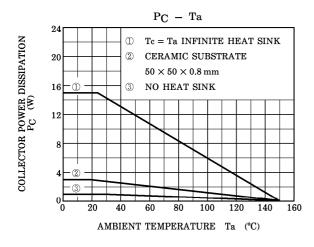
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 160 \text{ V}, I_{E} = 0$	_	_	1.0	$\mu$ <b>A</b>
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = 5 V, I_{C} = 0$	_	_	1.0	$\mu$ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{C} = 10 \text{ mA}, I_{B} = 0$	160	_	_	v
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	$I_{\mathrm{E}} = 1  \mathrm{mA}, \; I_{\mathrm{C}} = 0$	5	_	_	V
DC Current Gain	h <sub>FE</sub> (Note)	$V_{CE} = 5 \text{ V}, I_{C} = 100 \text{ mA}$	70	_	240	
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	$I_{\rm C} = 500  {\rm mA}, \ I_{\rm B} = 50  {\rm mA}$	_	_	1.5	V
Base-Emitter Voltage	$ m V_{BE}$	$V_{CE} = 5 \text{ V}, I_{C} = 500 \text{ mA}$	_	_	1.0	V
Transition Frequency	$\mathbf{f_{T}}$	$V_{CE} = 10 \text{ V}, I_{C} = 100 \text{ mA}$	_	100	_	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$	_	25	_	pF

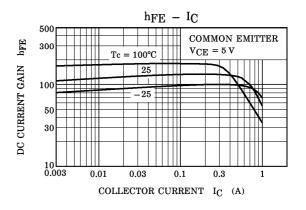
(Note):  $h_{FE}$  Classification  $O: 70\sim140, Y: 120\sim240$ 

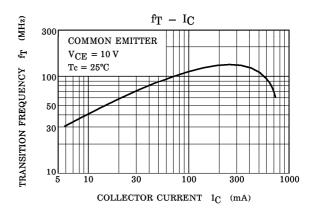
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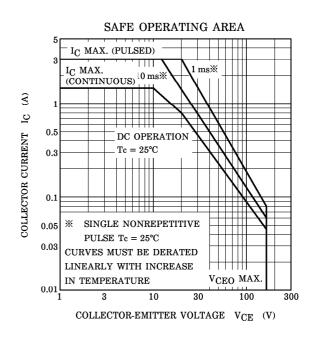












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